

200mW High Speed SMD Switching Diode

FEATURES

- Low power loss, high efficiency
- Ideal for automated placement
- High surge current capability
- Moisture sensitivity level: level 1, per J-STD-020
- Compliant to RoHS directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

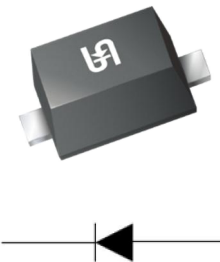
APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- Lighting application
- On-board DC/DC converter

MECHANICAL DATA

- Case: SOD-323F
- Molding compound meets UL 94 V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 1A whisker test
- Polarity: Indicated by cathode band
- Weight: 4.85 ± 0.5 mg

KEY PARAMETERS		
PARAMETER	VALUE	UNIT
V_{RRM}	100	V
V_F at $I_F=100mA$	1.0	V
T_J MAX.	150	°C
Package	SOD-323F	
Configuration	Single die	



ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)					
PARAMETER	SYMBOL	1N4148 WS	1N4448 WS	1N914B WS	UNIT
Marking code on the device		S1	S2	S3	
Power dissipation	P_D	200			mW
Repetitive peak reverse voltage	V_{RRM}	100			V
Forward current	I_F	150			mA
Non-repetitive peak forward current	I_{FRM}	300			mA
Junction temperature range	T_J	-65 to +150			°C
Storage temperature range	T_{STG}	-65 to +150			°C

THERMAL PERFORMANCE			
PARAMETER	SYMBOL	TYP	UNIT
Junction-to-ambient thermal resistance	$R_{\theta JA}$	625	°C/W

ELECTRICAL SPECIFICATIONS ($T_A = 25^\circ\text{C}$ unless otherwise noted)					
PARAMETER	CONDITIONS	SYMBOL	MIN	MAX	UNIT
Forward voltage ⁽¹⁾	1N4448WS, 1N914BWS $I_F = 5 \text{ mA}, T_J = 25^\circ\text{C}$	V_F	0.62	0.72	V
	1N4148WS $I_F = 10 \text{ mA}, T_J = 25^\circ\text{C}$		-	1.00	
	1N4448WS, 1N914BWS $I_F = 100 \text{ mA}, T_J = 25^\circ\text{C}$		-	1.00	
Reverse voltage	$I_R = 5 \mu\text{A}, T_J = 25^\circ\text{C}$	V_R	75	-	V
	$I_R = 100 \mu\text{A}, T_J = 25^\circ\text{C}$		-	100	
Reverse current @ rated V_R ⁽²⁾	$V_R = 20 \text{ V}, T_J = 25^\circ\text{C}$	I_R	-	25	nA
	$V_R = 75 \text{ V}, T_J = 25^\circ\text{C}$		-	5	μA
Junction capacitance	1 MHz, $V_R = 0 \text{ V}$	C_J	-	4	pF
Reverse recovery time	$I_F = 10 \text{ mA}, I_R = 60 \text{ mA}, R_L = 100 \Omega,$ $I_{RR} = 1 \text{ mA}$	t_{rr}	-	4	ns

Notes:

1. Pulse test with $PW = 0.3 \text{ ms}$
2. Pulse test with $PW = 30 \text{ ms}$

ORDERING INFORMATION		
PART NO.	PACKAGE	PACKING
1N4148WS RRG	SOD-323F	3K / 7" Reel
1N4148WS RR	SOD-323F	3K / 7" Reel
1N4148WS R9G	SOD-323F	10K / 13" Reel
1N4148WS R9	SOD-323F	10K / 13" Reel
1N4448WS RRG	SOD-323F	3K / 7" Reel
1N4448WS RR	SOD-323F	3K / 7" Reel
1N4448WS R9G	SOD-323F	10K / 13" Reel
1N4448WS R9	SOD-323F	10K / 13" Reel
1N914BWS RRG	SOD-323F	3K / 7" Reel
1N914BWS RR	SOD-323F	3K / 7" Reel
1N914BWS R9G	SOD-323F	10K / 13" Reel
1N914BWS R9	SOD-323F	10K / 13" Reel

CHARACTERISTICS CURVES

($T_A = 25^\circ\text{C}$ unless otherwise noted)

Fig. 1 Forward Voltage VS. Forward Current

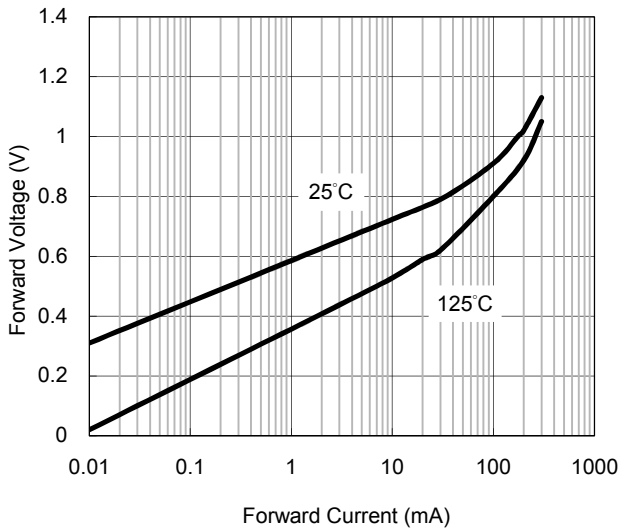


Fig. 2 Reverse Current vs Reverse Voltage

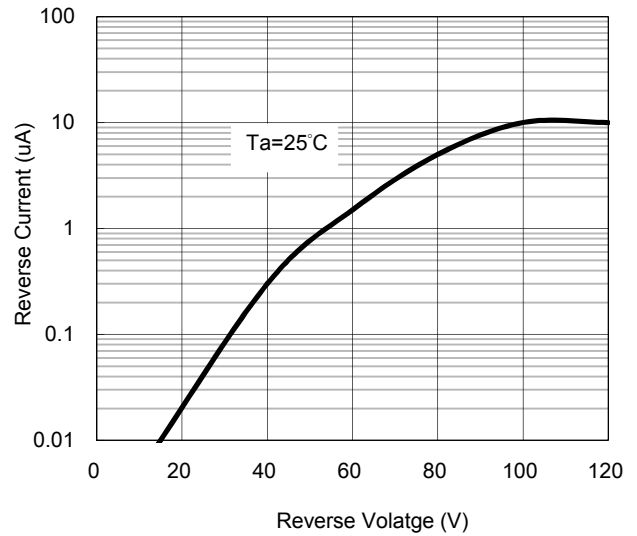


Fig. 3 Admissible Power Dissipation Curve

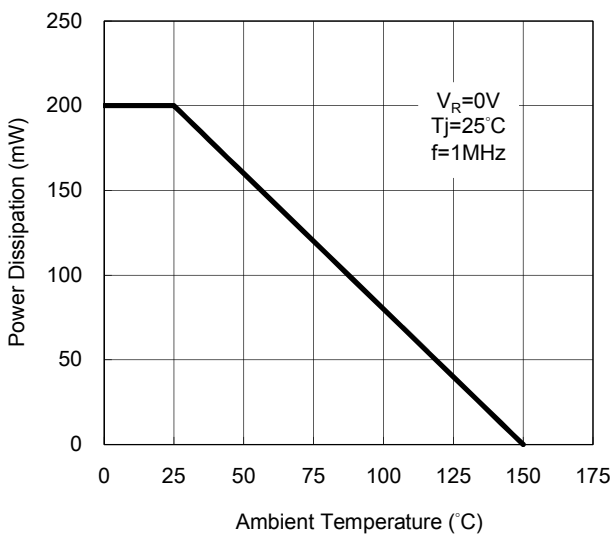
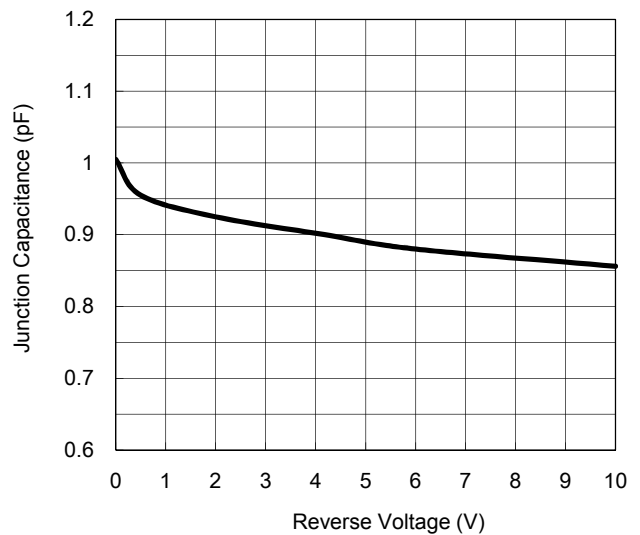
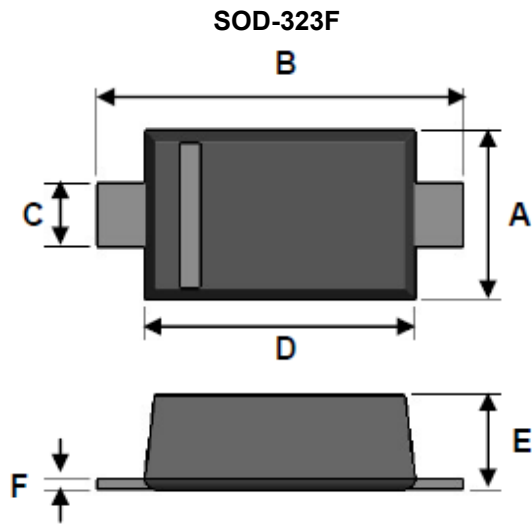


Fig. 4 Typical Junction Capacitance

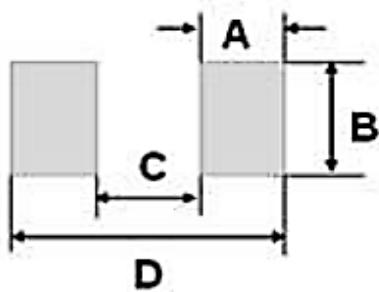


PACKAGE OUTLINE DIMENSION



DIM.	Unit (mm)		Unit (inch)	
	Min	Max	Min	Max
A	1.15	1.35	0.045	0.053
B	2.30	2.80	0.091	0.110
C	0.25	0.40	0.010	0.016
D	1.60	1.80	0.063	0.071
E	0.80	1.10	0.031	0.043
F	0.05	0.25	0.002	0.010

SUGGEST PAD LAYOUT



DIM.	Unit (mm)	Unit (inch)
	Typ.	Typ.
A	0.63	0.025
B	0.83	0.033
C	1.60	0.063
D	2.86	0.113

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